



- 2. Figure 2 is the phase diagram of Na and K.
 - (a) What kind of reaction at point p and c? And state the reaction equation. (5%)
 - (b) Consider a specimen at point g with a composition of Na₂K, state the reaction sequence (at points of f, e, b, n,and a) as the specimen is cooled from g to a. (5%)



Fig.2 (背面仍有題目.請繼續作答)

國立成功大學103學年度碩士班招生考試試題

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系所組別: 資源工程學系乙組

考試科目: 物理化學

考試日期:0222、節次:3

※ 考生請注意:本試題不可使用計算機。 請於答案卷(卡)作答,於本試題紙上作答者,不予計分。

- 3. Plot a schematic diagram to explain the electric double layer and zeta potential. (10%)
- 4. A useful adsorption isotherm given by Brunauer, Emmett and Teller (BET) is expressed as:

$$\frac{1}{v\left[(p_0/p) - 1\right]} = \frac{c - 1}{v_{\rm m}c} \left(\frac{p}{p_0}\right) + \frac{1}{v_mc}.$$
 (1)

where P and P_0 are the equilibrium and the saturation pressure of adsorbates at the temperature of adsorption, v is the adsorbed gas quantity (for example, in volume units), and v_m is the monolayer adsorbed gas quantity. c is the BET constant.

- (a) Suggest a method to test the applicability of equation (1), when
 v values are known at various pressures.(5%)
- (b) Show that Eq.(1) reduces to Langmuir isotherm when $P_0 \ge P$. (5%)
- (c) Show that for a small coverage of a system which obeys the Langmuir equation, the plot of $\ln(\theta/P)$ against CP/P0 is linear and has a slope of -1. (θ is the fraction of covered surface). (5%)
- 5. Explain why immiscible solution becomes complete miscible at a sufficiently high temperature in terms of Gibbs free energy. (5%)
- 6. For the cell Ag(s)|AgCl(s)| HCl(aq)|Hg₂Cl₂(s)|Hg(l), emf= 0.0455 volt at 25°C and temperature coefficient $(\partial E/\partial T) = 0.338$ mV/K.
 - (a) Write the individual electrode reactions and the overall cell reaction. (5%)
 - (b) Evaluate △G, △H and △S for the cell reaction at 25°C for 1 F. (15%)
- 7. Determine the activation energy (E_A) for a reaction which triples upon a temperature increase from 20°C to 40°C. (10%)
- 8. Explain the difference among the insulators, n-type semiconductors, p-type semiconductors and metals in terms of band structures. (12%)
- 9. Use the Gibbs-Helmoltz equation

$$\left(\frac{\partial(\Delta G^{\ominus}/T)}{\partial T}\right)_{p} = -\frac{\Delta H}{T^{2}}$$
⁽²⁾

to derive the Van't Hoff equation. (8%)

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